

HMC464LP5

Data Sheet

GaAs PHEMT MMIC POWER AMPLIFIER, 2.0 - 20.0 GHz

Manufacturers Analog Devices, Inc

Package/Case QFN32

Product Type Amplifier ICs

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for HMC464LP5 or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The HMC464LP5(E) is a GaAs MMIC PHEMT Distributed Power Amplifier in leadless 5x5 mm surface mount package which operates between 2 and 20 GHz. The amplifier provides 14 dB of gain, +30 dBm output IP3 and +26 dBm of output power at 1 dB gain compression while requiring 290 mA from a +8V supply. Gain flatness is good from 2 - 18 GHz making the HMC464LP5(E)ideal for EW, ECM and radar driver amplifiers as well as test equipment applications. The wideband amplifier I/O's are internally matched to 50 Ohms.

Features Application

Output Power: +26 dBm P1dB Telecom Infrastructure

Gain: 14 dB Microwave Radio & VSAT

Output IP3: +30 dBm Military EW, ECM & C³I

Supply Voltage: +8V @ 290 mA Test Instrumentation

50 Ohm Matched Input/Output Fiber Optics

25 mm² Leadless SMT Package





Related Products



HMC591LP5E

Analog Devices, Inc QFN32



LTC6102HMS8#PBF

Analog Devices, Inc 8MSOP



LTC6102HMS8

Analog Devices, Inc MSOP8



LTC6102HMS8-1#PBF

Analog Devices, Inc 8-MSOP



HMC589AST89E

Analog Devices, Inc SOT-89



HMC902LP3E

Analog Devices, Inc QFN-16



LT6375HMS#PBF

Analog Devices, Inc 16MSOP



LTC6081HMS8#PBF

Analog Devices, Inc 8MSOP